



IXYS
A Littelfuse Technology

Date:- 30 Aug, 2019

Data Sheet Issue:- P1

Tentative data

Insulated Gate Bi-Polar Transistor Type T0140QC33G

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V _{CES}	Collector – emitter voltage	3300	V
V _{DC link}	Permanent DC voltage for 100 FIT failure rate.	1800	V
V _{GES}	Peak gate – emitter voltage	±20	V

	RATINGS	MAXIMUM LIMITS	UNITS
I _{C(DC)}	DC collector current, IGBT	140	A
I _{CRM}	Repetitive peak collector current, t _p =1ms, IGBT	280	A
I _{F(DC)}	Continuous DC forward current, Diode	140	A
I _{FRM}	Repetitive peak forward current, t _p =1ms, Diode	280	A
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{RM} =60%V _{RRM} , Diode (Note 4)	880	A
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{RM} ≤10V, Diode (Note 4)	970	A
P _{MAX}	Maximum power dissipation, IGBT (Note 2)	0.93	kW
P _D	Maximum power dissipation, Diode (Note 2)	0.58	kW
(di/dt) _{cr}	Critical diode di/dt (note 3)	350	A/μs
T _j	Operating temperature range.	-40 to +125	°C
T _{stg}	Storage temperature range.	-40 to +125	°C

Notes: -

- 1) Unless otherwise indicated T_j = 125°C.
- 2) T_{sink} = 25°C, double side cooled.
- 3) Maximum commutation loop inductance 1000nH.
- 4) Half-sinewave, 125°C T_j initial.

Characteristics

IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_{CE(sat)}$	Collector – emitter saturation voltage	-	2.64	2.95	$I_C = 140A, V_{GE} = 15V, T_j = 25^\circ C$	V
		-	3.35	3.70	$I_C = 140A, V_{GE} = 15V$	V
V_{T0}	Threshold voltage	-	-	1.63	Current range: 47 – 140A	V
r_T	Slope resistance	-	-	14.8		m Ω
$V_{GE(TH)}$	Gate threshold voltage	-	5.2	-	$V_{CE} = V_{GE}, I_C = 12mA$	V
I_{CES}	Collector – emitter cut-off current	-	1.5	11	$V_{CE} = V_{CES}, V_{GE} = 0V$	mA
I_{GES}	Gate leakage current	-	-	± 3	$V_{GE} = \pm 20V$	μA
C_{ies}	Input capacitance	-	20	-	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$	nF
$t_{d(on)}$	Turn-on delay time	-	1.4	-	$I_C = 140A, V_{CE} = 1800V, di/dt = 300A/\mu s$	μs
$t_r(V)$	Rise time	-	1.9	-		μs
$Q_{g(on)}$	Turn-on gate charge	-	2.7	-	$V_{GE} = \pm 15V, L_s = 1.5\mu H$	μC
E_{on}	Turn-on energy	-	0.37	-	$R_{G(ON)} = 15\Omega, R_{G(OFF)} = 100\Omega, C_{GE} = 56nF$	J
$t_{d(off)}$	Turn-off delay time	-	4.7	-	Integral diode used as freewheel diode (Note 3, 4 & 5)	μs
$t_f(I)$	Fall time	-	1.1	-		μs
$Q_{g(off)}$	Turn-off gate charge	-	2.0	-		μC
E_{off}	Turn-off energy	-	0.38	-		J
I_{SC}	Short circuit current	-	550	-	$V_{GE} = +15V, V_{CC} = 1800V, V_{CEmax} \leq V_{CES}, t_p \leq 10\mu s$	A

Diode Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
V_F	Forward voltage	-	2.65	2.95	$I_F = 140A, T_j = 25^\circ C$	V
		-	3.0	3.3	$I_F = 140A$	V
V_{T0}	Threshold voltage	-	-	1.72	Current range 47 - 140A	V
r_T	Slope resistance	-	-	11.3		m Ω
I_{rm}	Peak reverse recovery current	-	100	-	$I_F = 140A, V_{GE} = \pm 15V, di/dt = 300A/\mu s$	A
Q_{rr}	Recovered charge	-	150	-		μC
t_{rr}	Reverse recovery time, 50% chord	-	1.9	-		μs
E_r	Reverse recovery energy	-	0.16	-		J

Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
R_{thJK}	Thermal resistance junction to sink, IGBT	-	-	108	Double side cooled	K/kW
		-	-	177	Collector side cooled	K/kW
		-	-	279	Emitter side cooled	K/kW
R_{thJK}	Thermal resistance junction to sink, Diode	-	-	172	Double side cooled	K/kW
		-	-	268	Cathode side cooled	K/kW
		-	-	478	Anode side cooled	K/kW
F	Mounting force	4.5	-	6	Note 2	kN
W_t	Weight	-	240	-		g

Notes:-

- 1) Unless otherwise indicated $T_j = 125^\circ C$.
- 2) Consult application note 2008AN01 for detailed mounting requirements
- 3) C_{GE} is additional gate – emitter capacitance added to output of gate drive
- 4) E_{on} integration time 15 μs from 10% rising I_G .
- 5) E_{off} integration time 15 μs from 90% falling V_{GE} .

Curves

Figure 1 – Typical collector-emitter saturation voltage characteristics

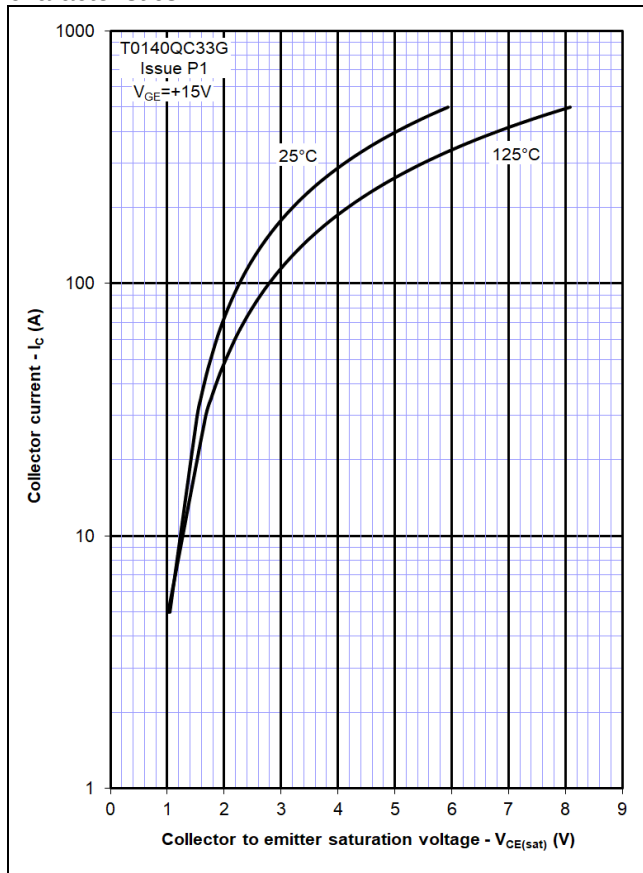


Figure 2 – Typical output characteristic

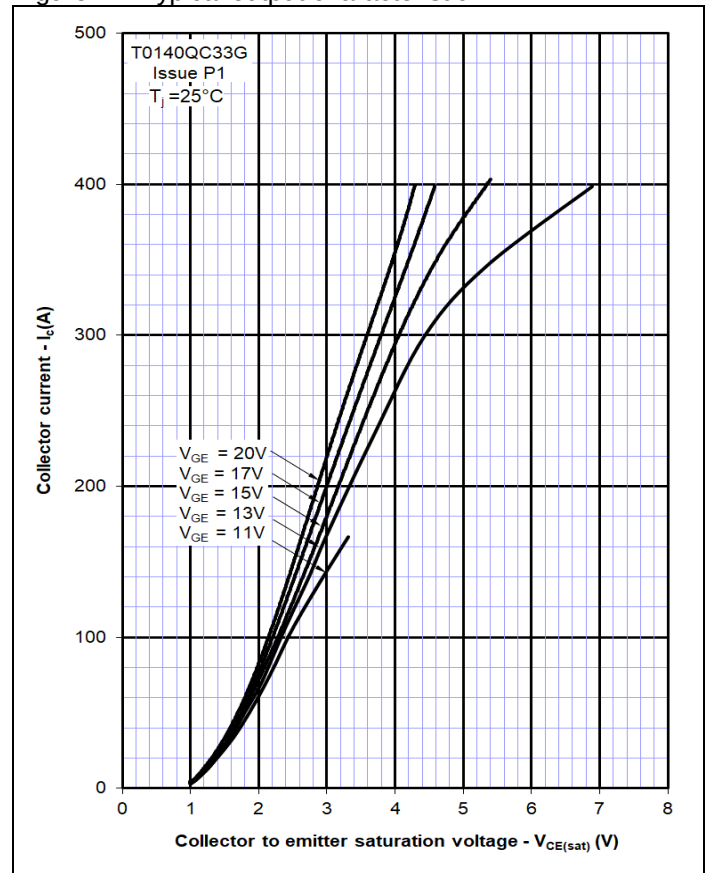


Figure 3 – Typical output characteristic

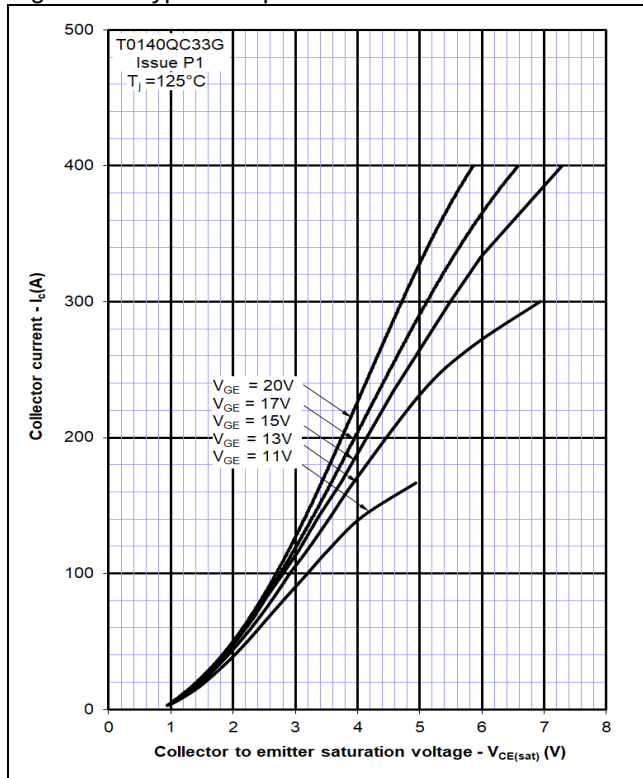


Figure 4 – Typical turn-on delay time vs gate resistance

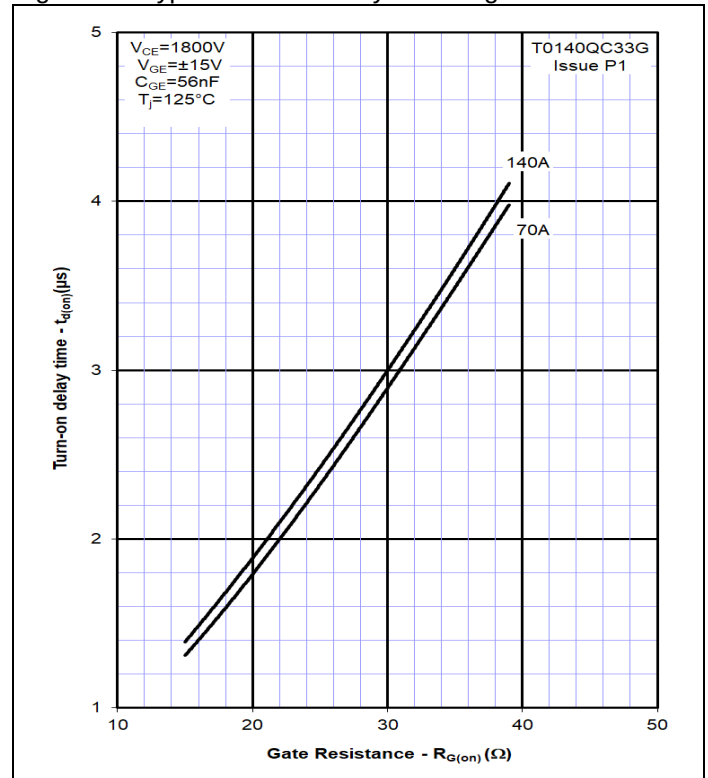


Figure 5 – Typical turn-off delay time vs. gate resistance

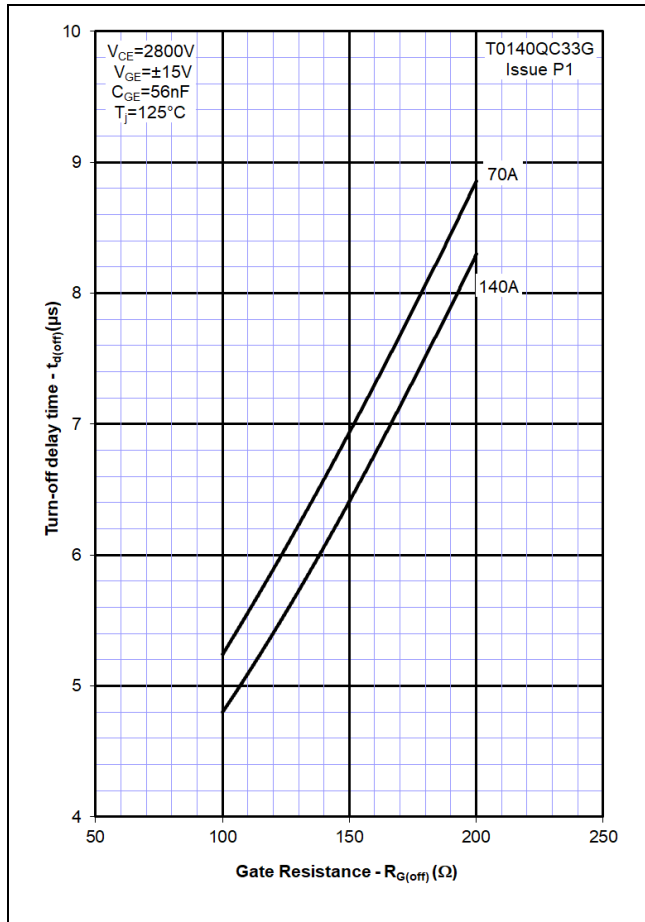


Figure 6 – Typical turn-on energy vs. collector current

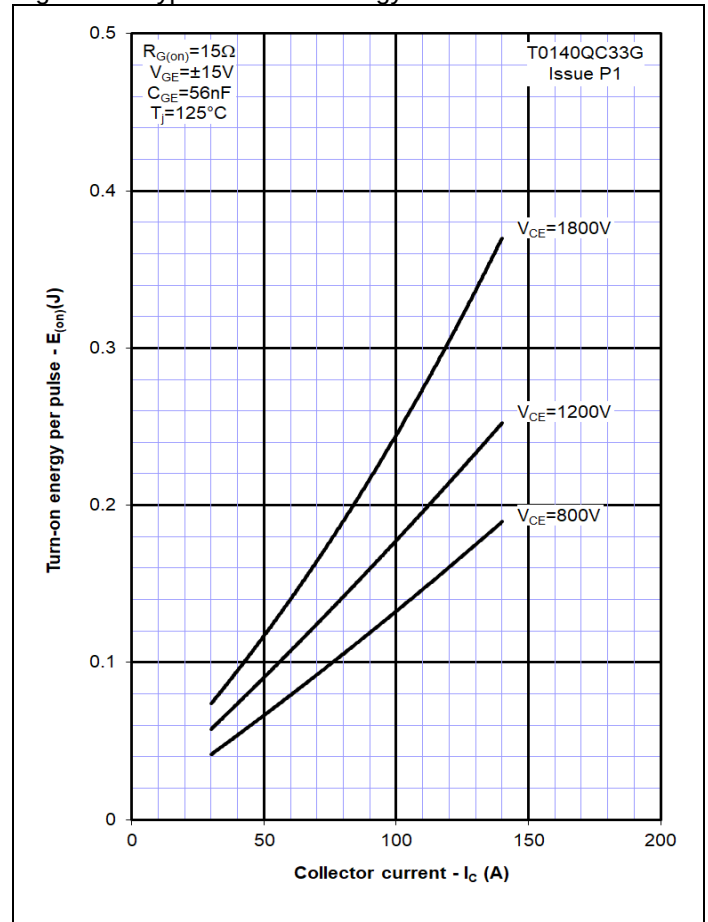


Figure 7 – Typical turn-on energy vs. di/dt

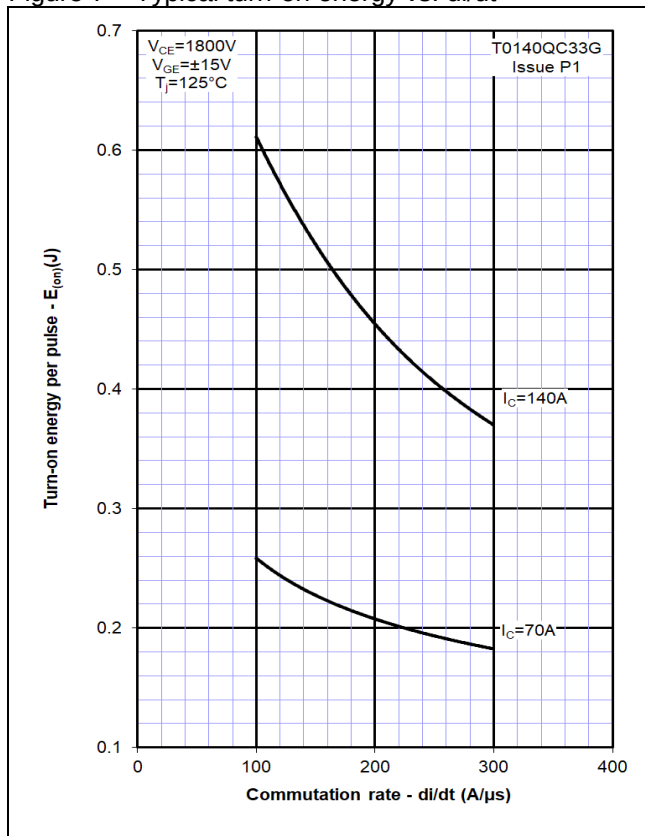


Figure 8 – Typical turn-off energy vs. collector current

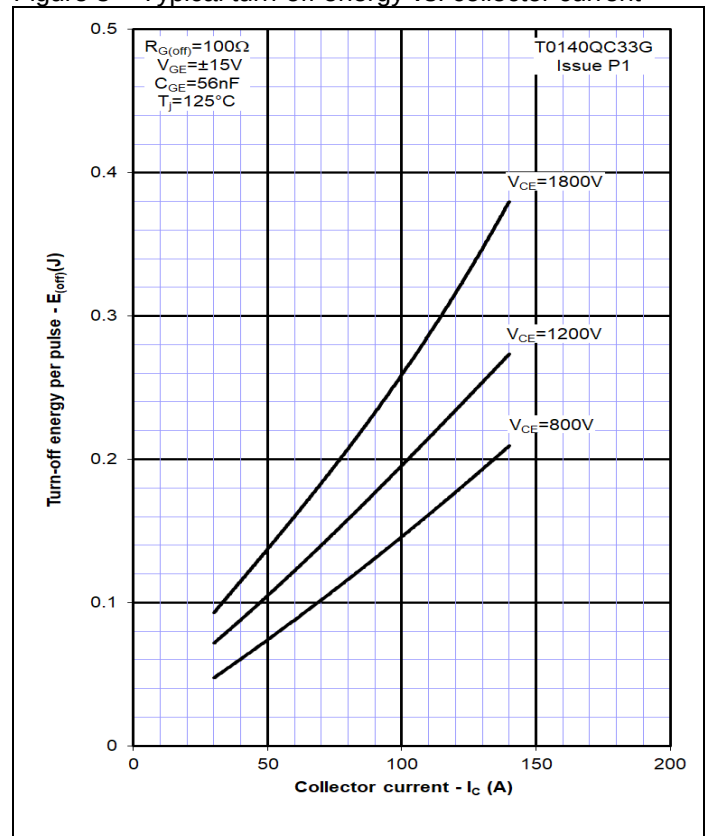


Figure 9 – Turn-off energy vs voltage

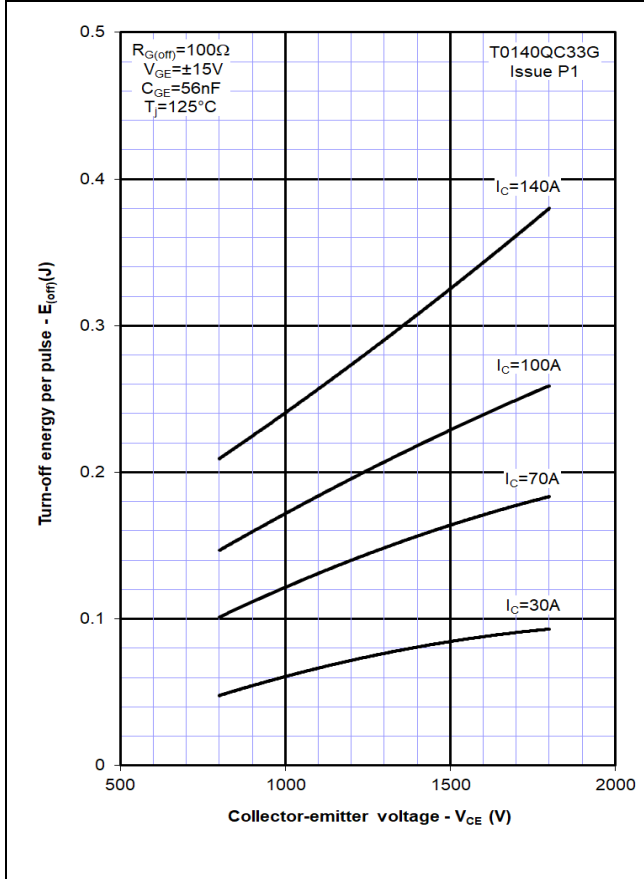


Figure 10 – Safe operating area (IGBT)

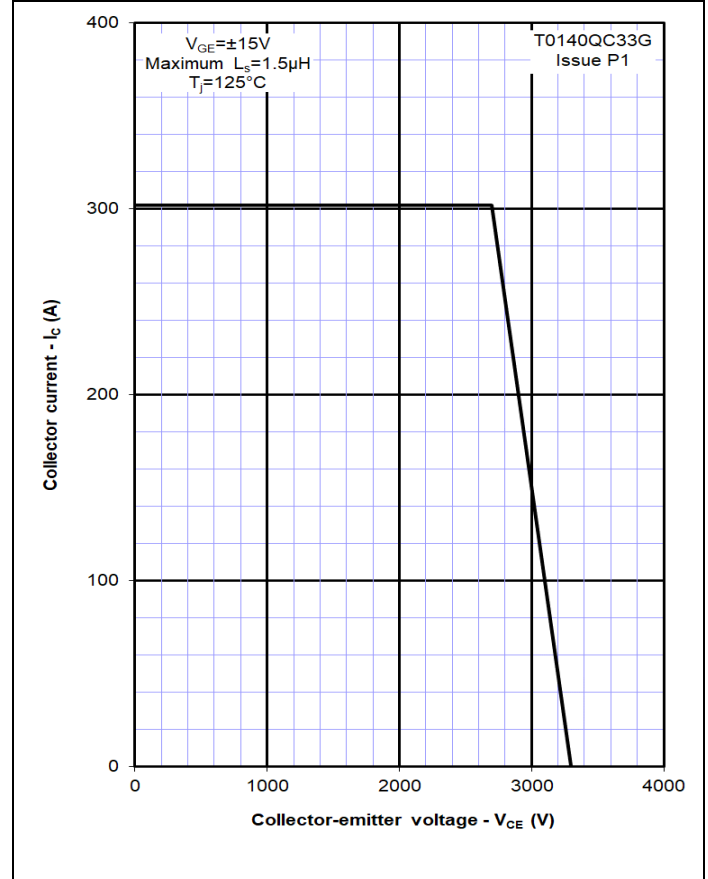


Figure 11 – Typical diode forward characteristics

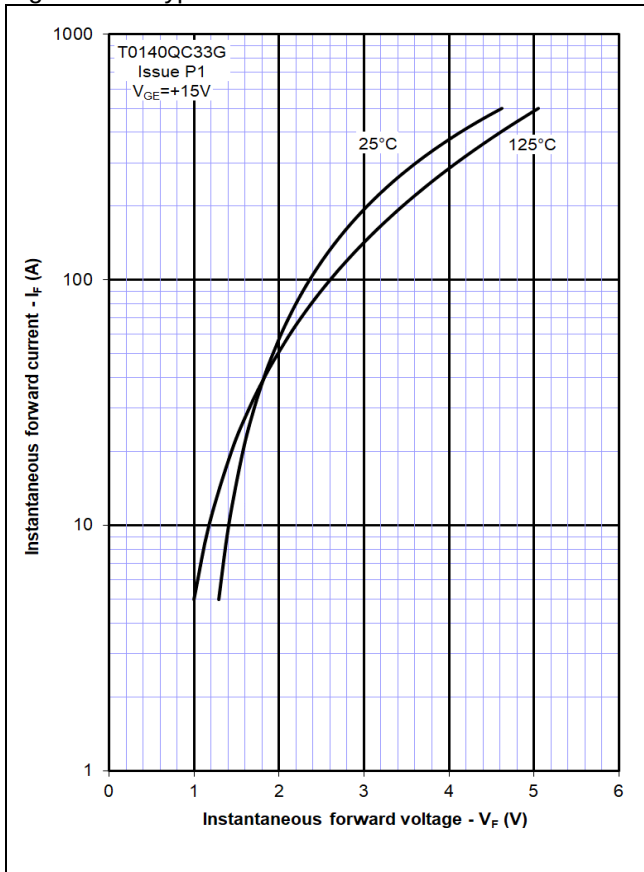


Figure 12 – Typical recovered charge

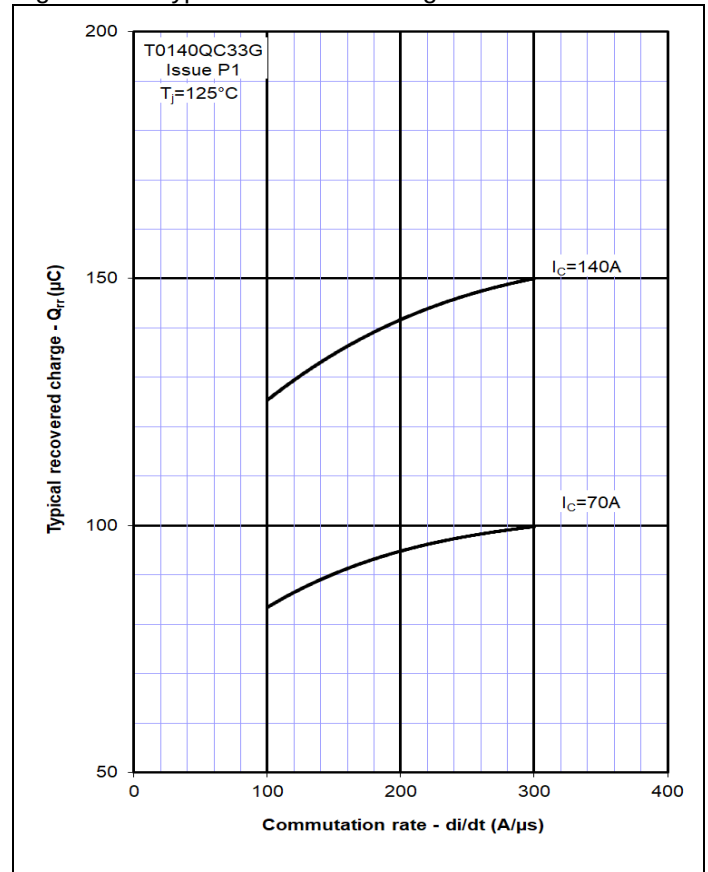


Figure 13 – Typical reverse recovery current

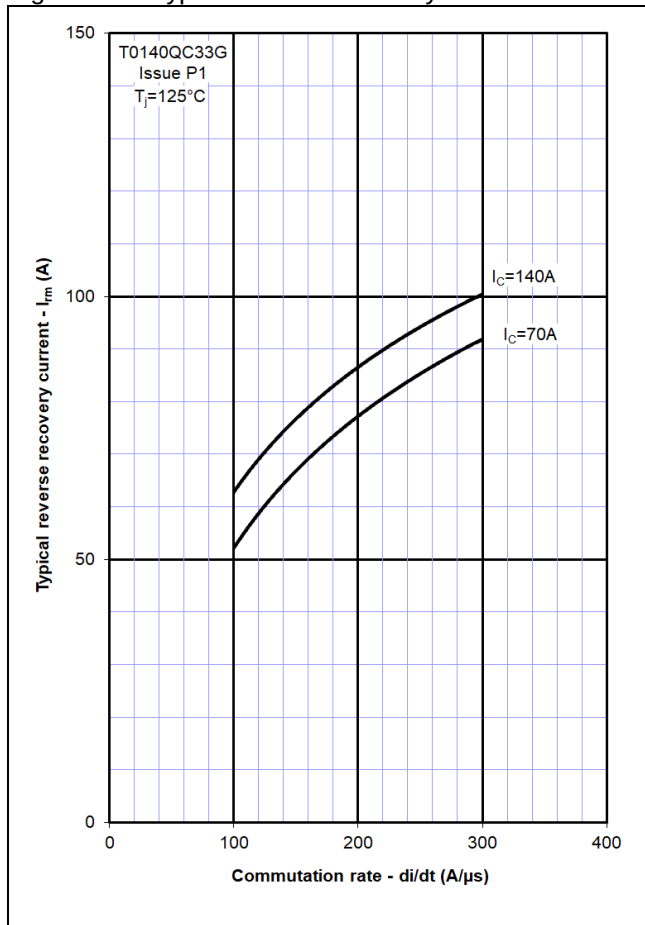


Figure 14 – Typical reverse recovery time

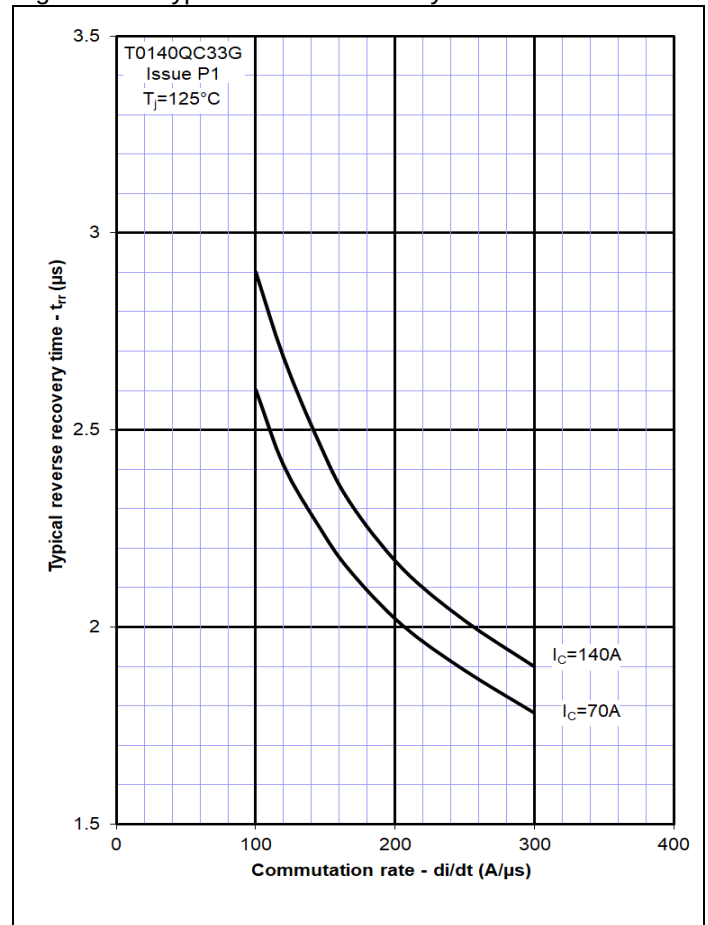


Figure 15 – Typical reverse recovery energy

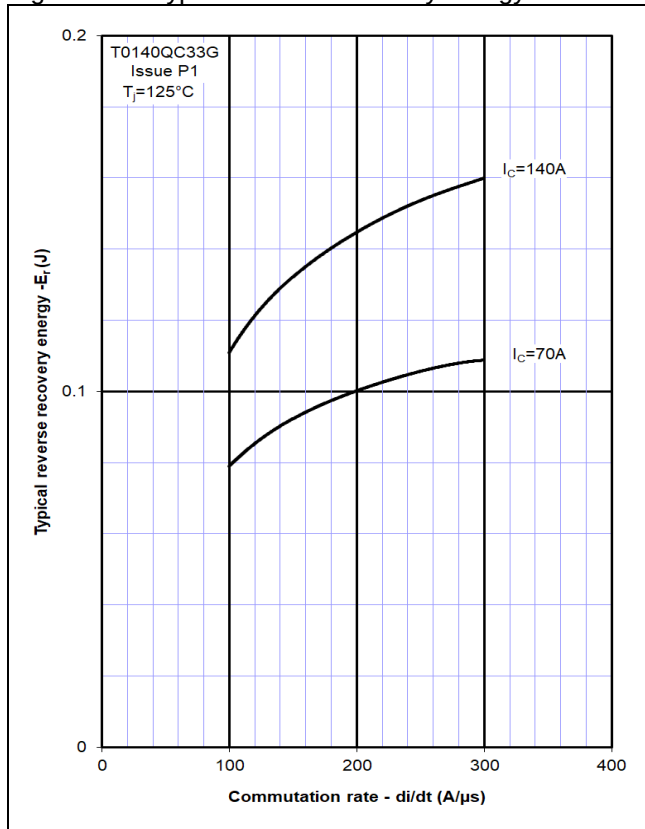


Figure 16 – Safe operating area (Diode)

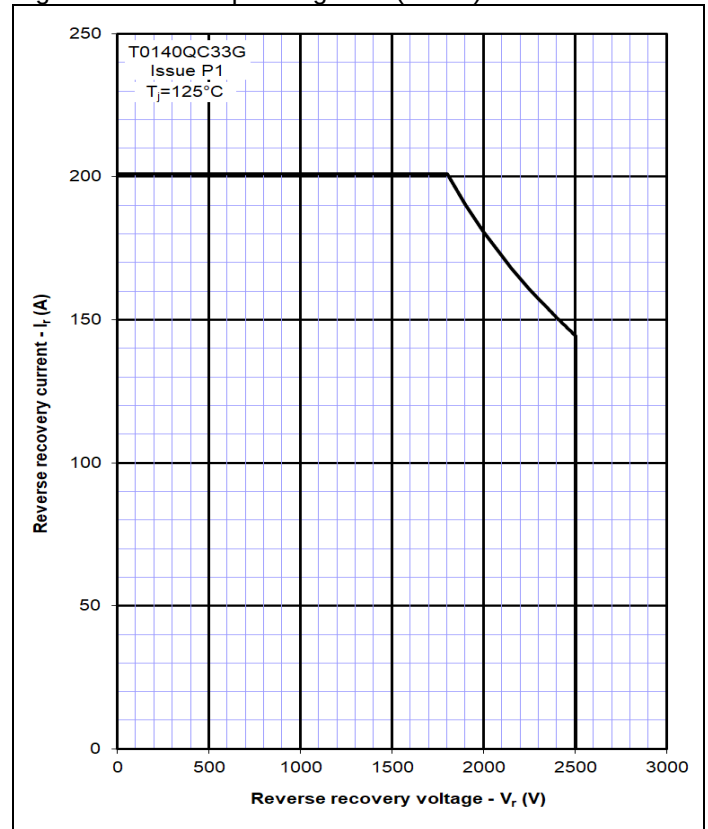


Figure 17 – Transient thermal impedance (IGBT)

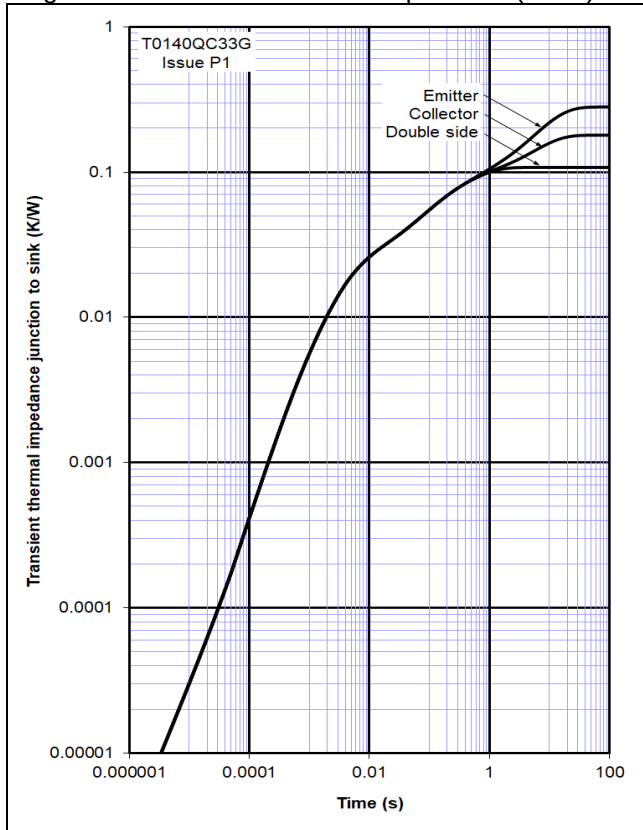
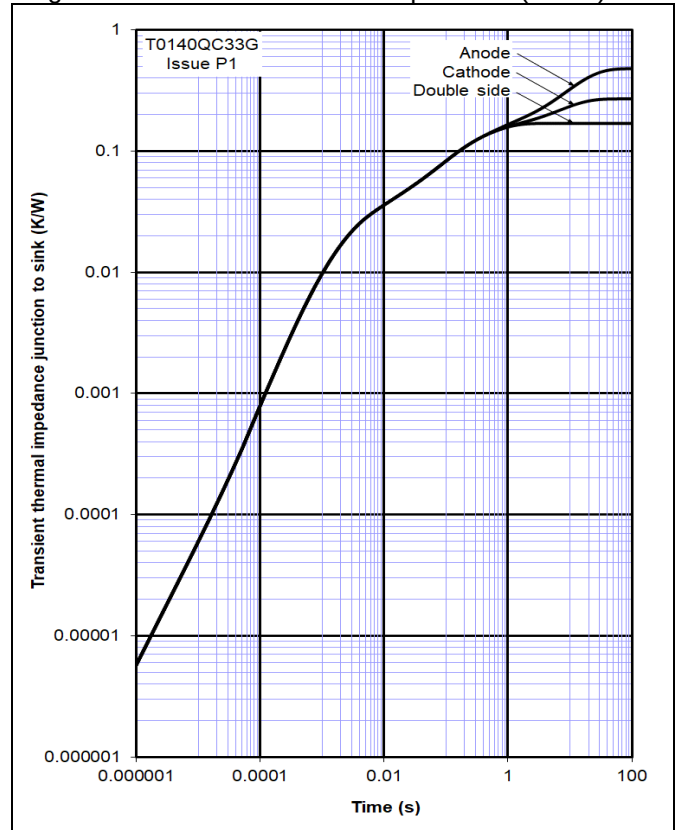
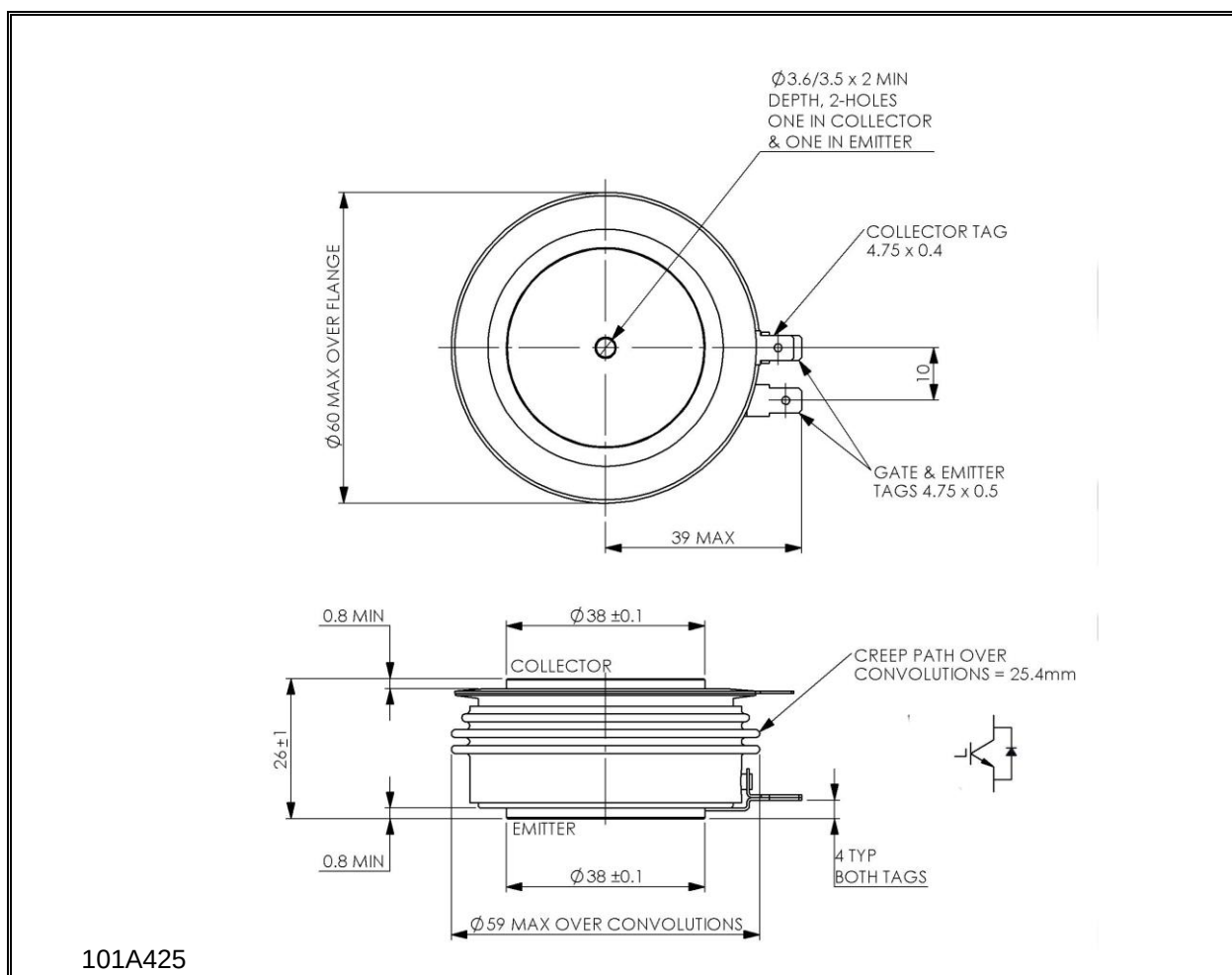


Figure 18 – Transient thermal impedance (Diode)



Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 10 digit code as below)

T0140	QC	33	G
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 33	Fixed format code

 Typical order code: T0140QC33G ($V_{CES} = 3300V$)

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